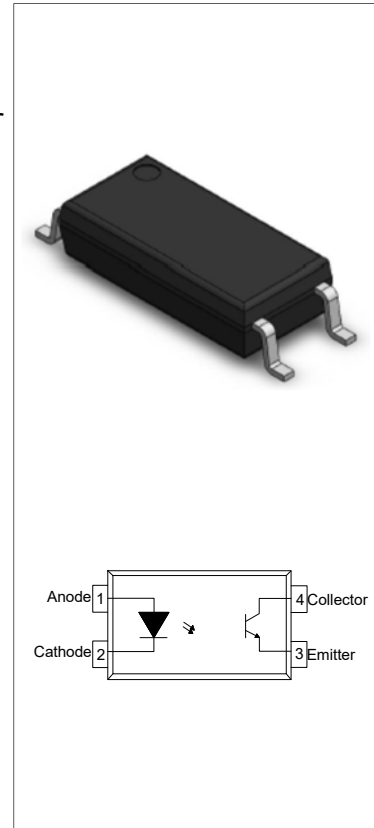


### DESCRIPTION:

The products are transistor opto-couplers in a plastic LSOP4 package. The device combines an AlGaAs infrared emitting diode as the emitter which is optically coupled to a silicon planar phototransistor detector. With the robust coplanar double mold structure, the device provides the most stable isolation feature. The products are widely used in switch mode power supplies, programmable controllers, household appliances, office equipment, etc.

### MAIN FEATURES

- High isolation 5000 VRMS
- DC input with transistor output
- Operating temperature range -40°C to 125°C
- RoHS & REACH Compliance
- HBM: H3A; MM: M4; CDM:C3
- CQC approved
- VDE approved
- UL approved



### ABSOLUTE MAXIMUM RATINGS (Temperature=25°C)

Parameter		Symbol	Value	Unit
Input	Forward Current	$I_F$	50	mA
	Peak Forward Current	$I_{FP}$	1 <sup>①</sup>	A
	Reverse Voltage	$V_R$	6	V
	Power Dissipation	$P_D$	75	mW
Output	Collector-emitter Voltage	$V_{CEO}$	80	V
	Emitter-collector Voltage	$V_{ECO}$	7	V
	Collector Current	$I_C$	50	mA
	Power Dissipation	$P_C$	150	mW
Total Power Dissipation		$P_{tot}$	225	mW
Isolation Voltage		$V_{iso}$	5000 <sup>②</sup>	Vrms
Operating Temperature		$T_{opr}$	-40~+125	°C
Junction Temperature		$T_j$	135	°C

Storage Temperature	T <sub>stg</sub>	-55~+125	°C
Soldering Temperature	T <sub>sol</sub>	260	°C

**NOTE1**: 100μs pulse, 100Hz frequency

**NOTE2**: AC for 1minute, R.H.=40~60%

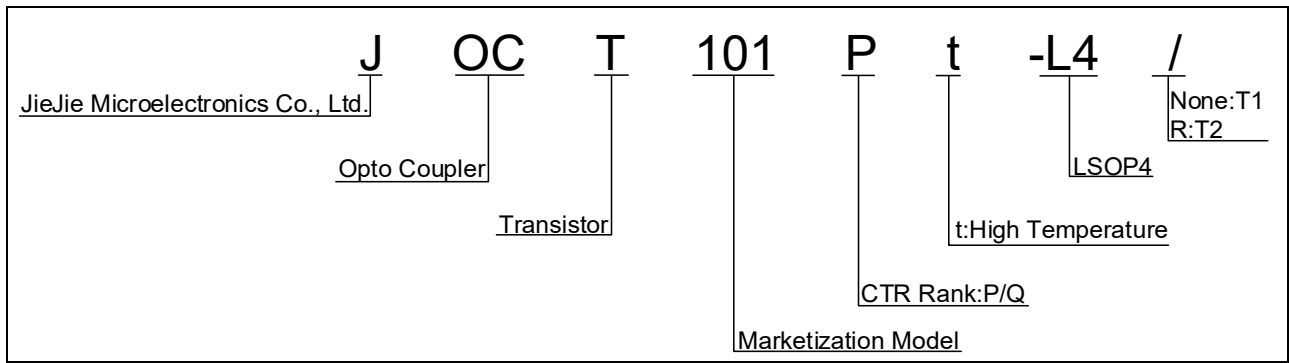
### ELECTRICAL CHARACTERISTICS (Temperature=25°C)

Parameter		Symbol	Condition	Min.	Typ.	Max.	Unit
Input	Forward Voltage	V <sub>F</sub>	I <sub>F</sub> =10mA	-	1.2	1.5	V
	Reverse Current	I <sub>R</sub>	V <sub>R</sub> =6V	-	-	1	μA
	Terminal Capacitance	C <sub>t</sub>	V=0, f=1MHz	-	30	250	pF
Output	Collector-Emitter dark current	I <sub>CEO</sub>	V <sub>CE</sub> =20V, I <sub>F</sub> =0	-	-	50	nA
	Collector-Emitter breakdown voltage	BV <sub>CEO</sub>	I <sub>C</sub> =0.1mA I <sub>F</sub> =0	80	-	-	V
	Emitter-Collector breakdown voltage	BV <sub>ECO</sub>	I <sub>E</sub> =0.1mA I <sub>F</sub> =0	7	-	-	V
Transfer Characteristics	Current transfer ratio	CTR	I <sub>F</sub> =5mA V <sub>CE</sub> =5V	100	-	400	%
	Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>F</sub> =10mA I <sub>C</sub> =1mA	-	0.1	0.2	V
	Isolation resistance	R <sub>IO</sub>	DC500V 40~60%R.H.	5×10 <sup>10</sup>	-	-	Ω
	Floating Capacitance	C <sub>IO</sub>	V=0, f=1MHz	-	0.6	1	pF
	Cut-off Frequency	f <sub>c</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =2mA R <sub>L</sub> =100Ω, -3dB	-	80	-	kHz
	Rise Time	t <sub>r</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =2mA R <sub>L</sub> =100Ω	-	4	18	μs
	Fall Time	t <sub>f</sub>		-	5	18	μs
	Turn On Time	t <sub>on</sub>		-	8	25	μs
Turn Off Time	t <sub>off</sub>	-		5	25	μs	

**NOTE1**: Rank Table of Current Transfer Ratio (Temperature=25°C)

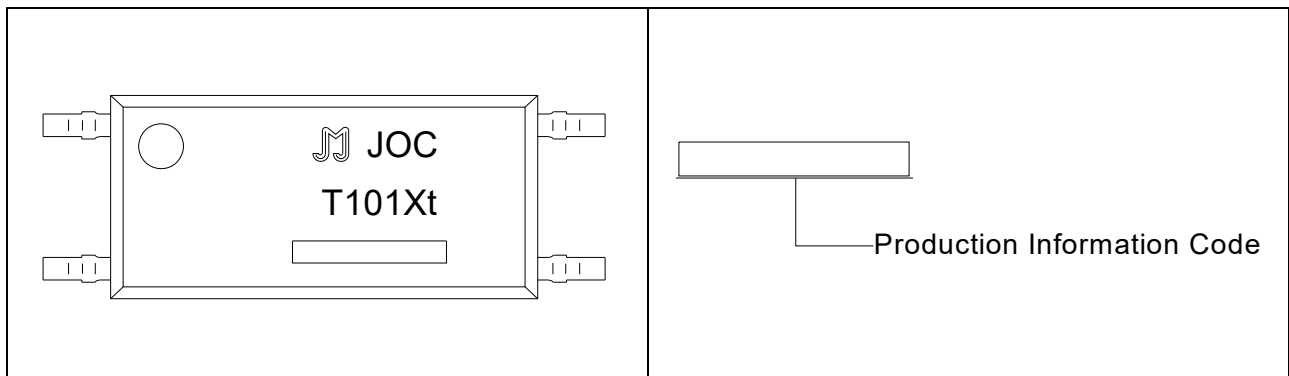
CTR Rank	Min. (%)	Max. (%)	Test Condition
JOCT101P	200	400	I <sub>F</sub> =0.5mA, V <sub>CE</sub> =5V
	200	400	I <sub>F</sub> =5mA, V <sub>CE</sub> =5V
JOCT101Q	100	300	I <sub>F</sub> =0.5mA, V <sub>CE</sub> =5V
	100	300	I <sub>F</sub> =5mA, V <sub>CE</sub> =5V

**ORDERING INFORMATION**



Packing Quantity			
Option	Quantity	Quantity – Inner box	Quantity –Outer box
LSOP4	3000 Units/Reel	2 Reels/Inner box	5 Inner box/Outer box =30k Units

**MARKING**



Characteristics Curves

FIG.1: Max. Allowable LED Forward Current vs. Ambient Temperature

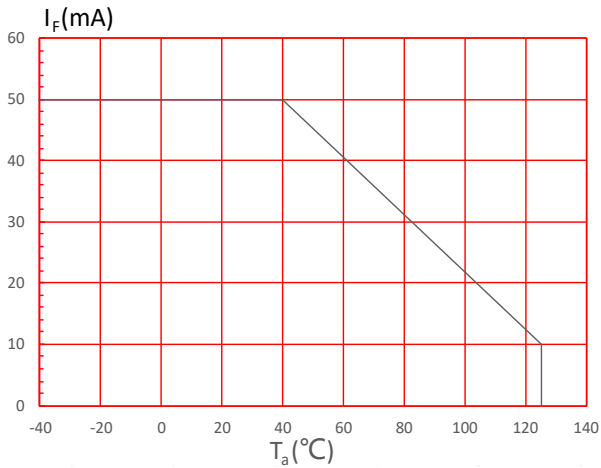


FIG.2: Collector Power Dissipation vs. Ambient Temperature

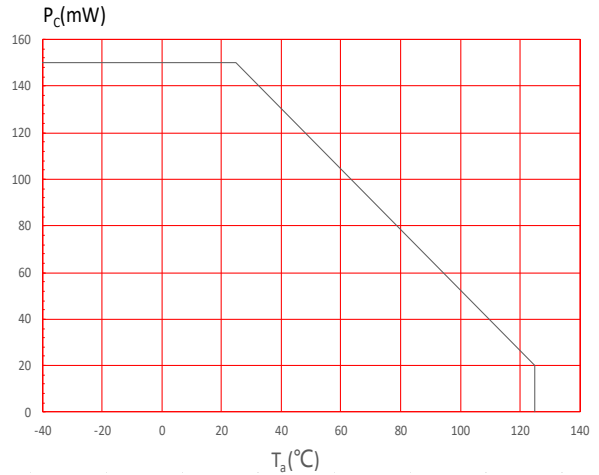


FIG.3: Forward Current vs. Forward Voltage

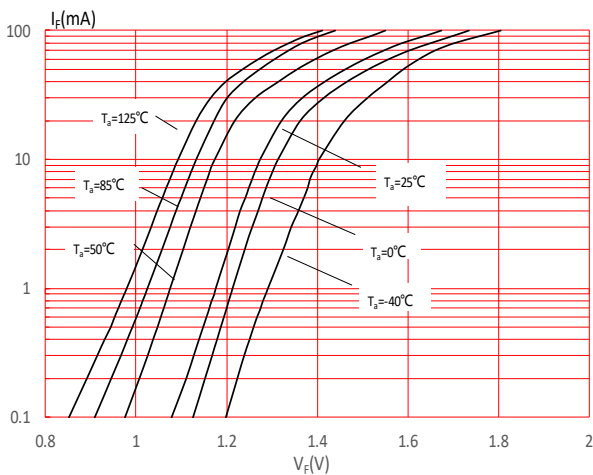


FIG.4: Normalized Collector Dark Current vs. Ambient Temperature

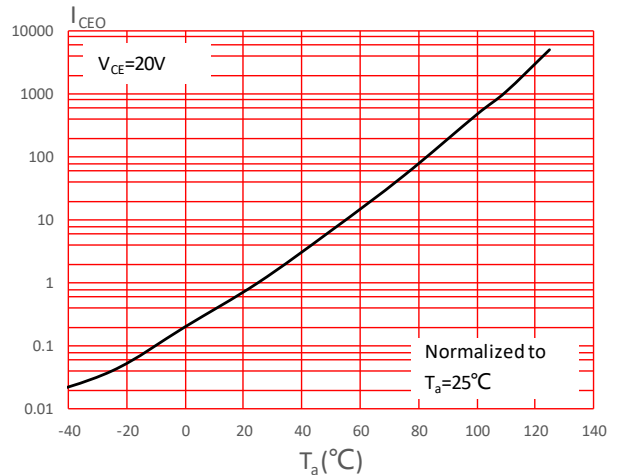


FIG.5: Collector Current vs. Collector-emitter Voltage

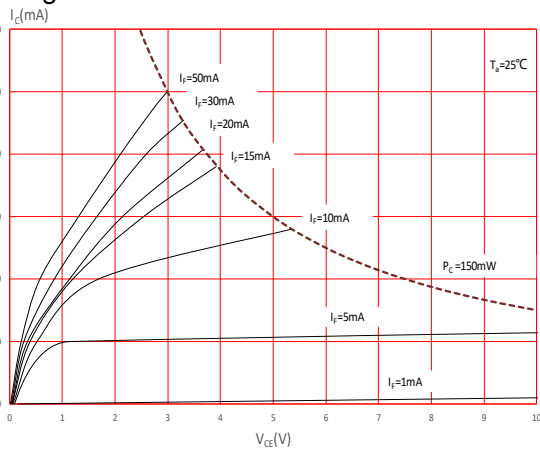
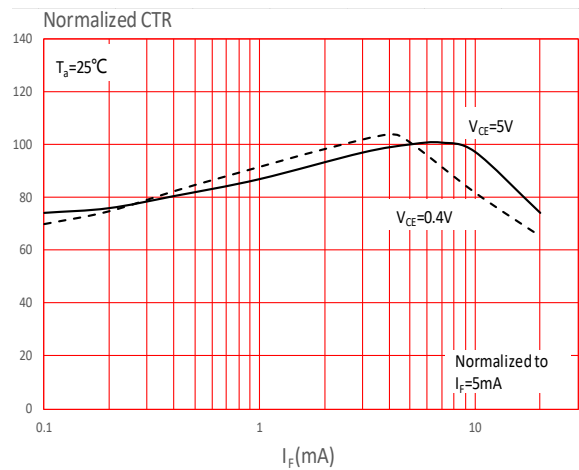
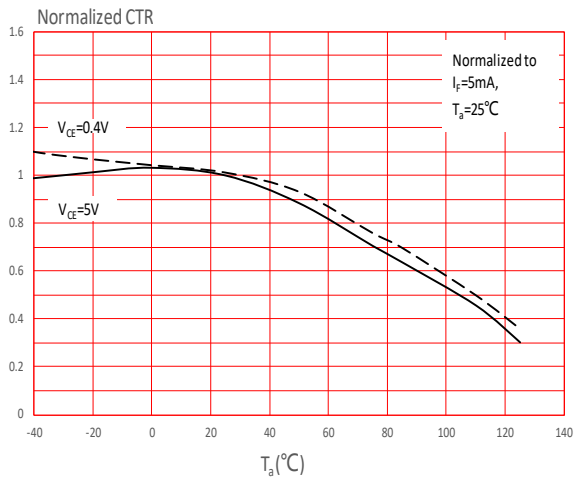


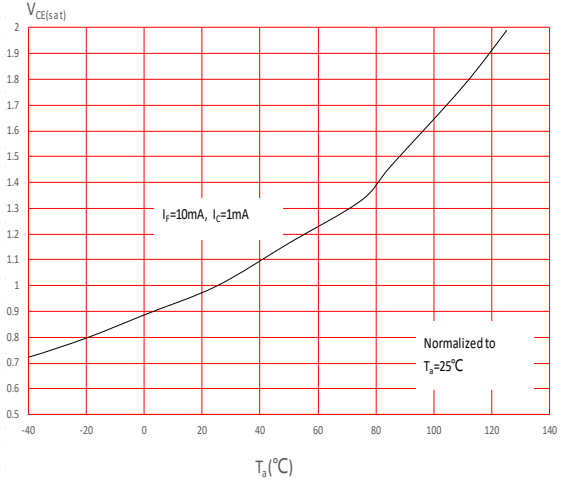
FIG.6: Normalized Current Transfer Ratio vs. Forward Current



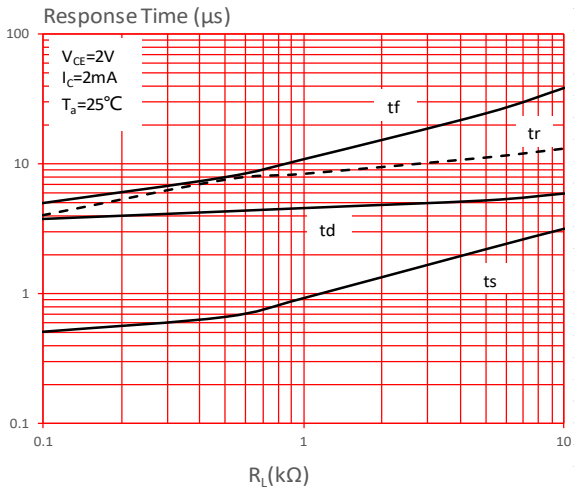
**FIG.7:** Normalized Current Transfer Ratio vs. Ambient Temperature



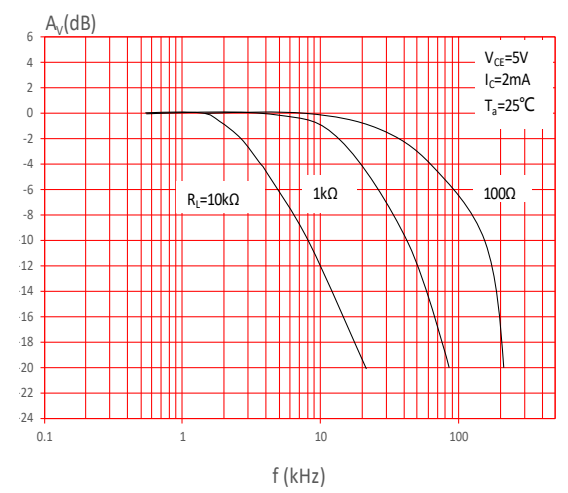
**FIG.8:** Normalized Collector-emitter Saturation Voltage vs. Ambient Temperature



**FIG.9:** Response Time vs. Load Resistance



**FIG.10:** Frequency Response



Test Circuits

FIG.11: Test Circuits of Response Time

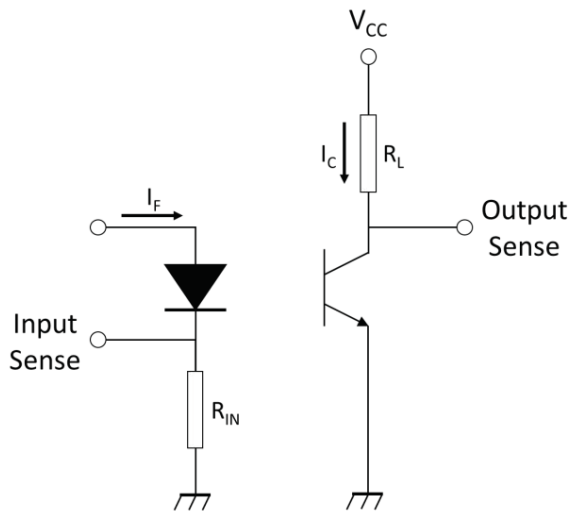


FIG.12: Curves of Response Time

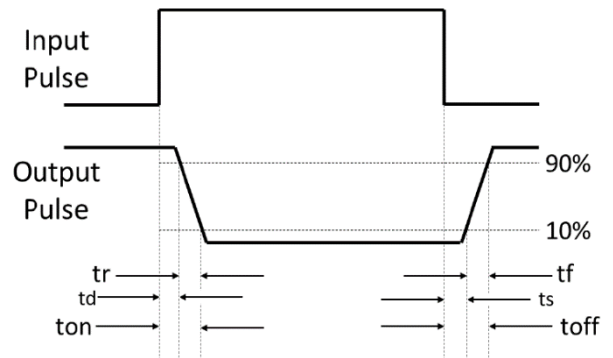
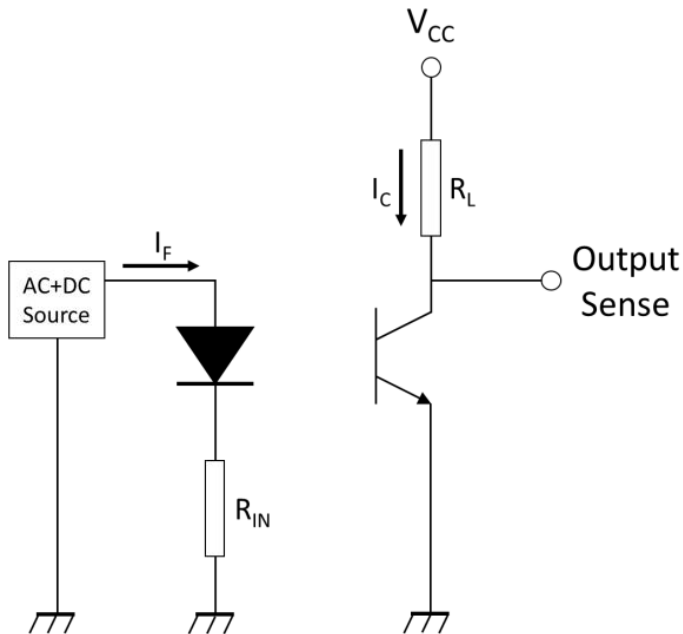
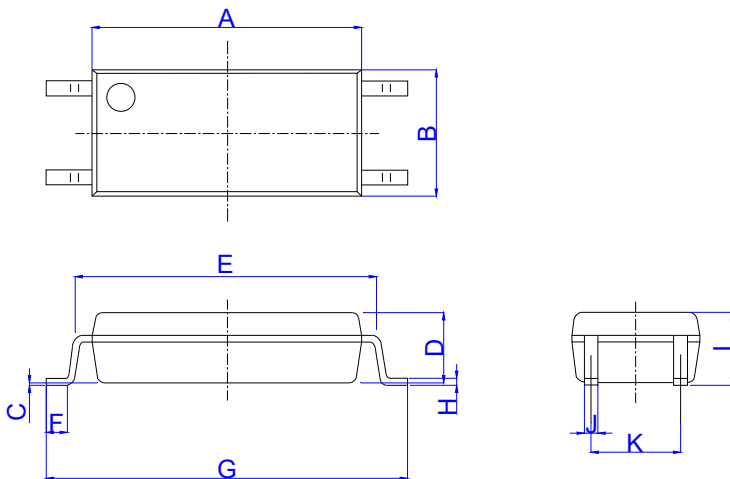


FIG.13: Test Circuits of Frequency Response

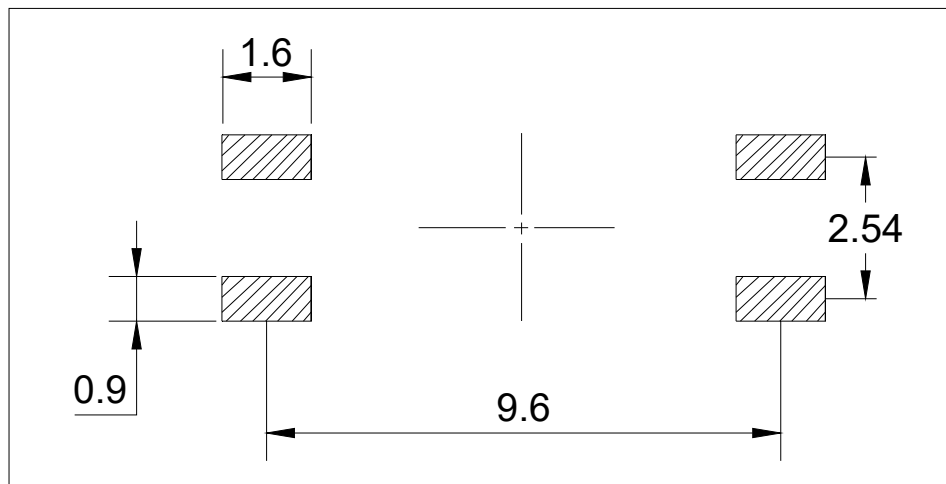


Package Dimension (Unit: mm)



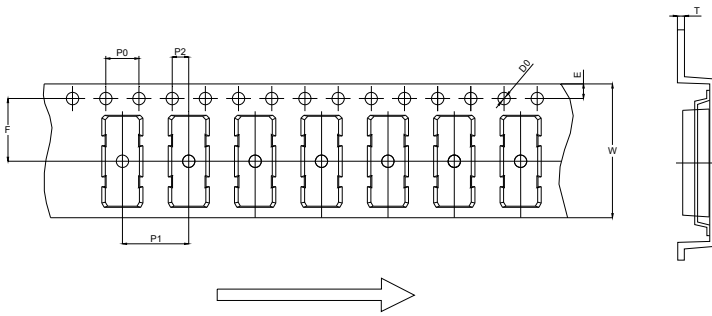
Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	7.40		7.80	0.291		0.307
B	3.40		3.80	0.134		0.150
C	0.00		0.20	0.000		0.008
D	1.80		2.20	0.071		0.087
E	8.10		8.70	0.319		0.343
F	0.40		1.00	0.016		0.039
G	9.90		10.50	0.390		0.413
H	0.10		0.30	0.004		0.012
I	1.80		2.40	0.071		0.094
J	0.25		0.55	0.010		0.022
K	2.29		2.79	0.090		0.110

RECOMMENDED SOLDER MASK (Dimensions in mm unless otherwise stated)



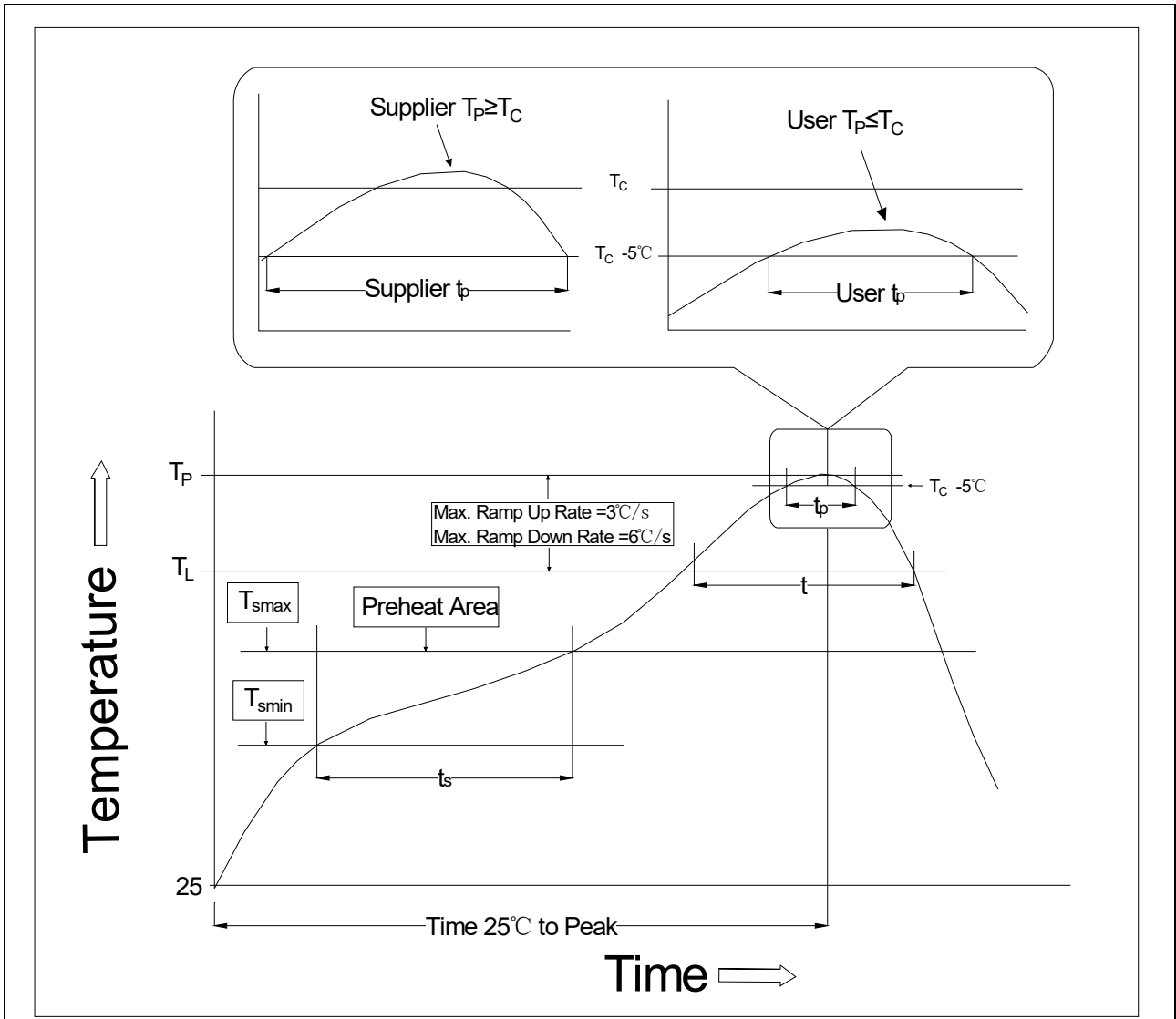
**CARRIER TAPE SPECIFICATIONS (Dimensions in mm unless otherwise stated)**

**Option None/R**



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
D0	1.50	1.55	1.60	0.059	0.061	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.90	2.00	2.10	0.075	0.079	0.083
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
T	0.35	0.40	0.45	0.014	0.016	0.018
W	15.80	16.00	16.20	0.622	0.630	0.638

REFLOW INFORMATION



Profile Feature	Sn-Pb Assembly Profile	Pb-Free Assembly Profile
Temperature Min. (T <sub>smin</sub> )	100	150°C
Temperature Max. (T <sub>smax</sub> )	150	200°C
Time (t <sub>s</sub> ) from (T <sub>smin</sub> to T <sub>smax</sub> )	60-120 seconds	60-120 seconds
Ramp-up Rate (t <sub>L</sub> to t <sub>P</sub> )	3°C/second max.	3°C/second max.
Liquidus Temperature (T <sub>L</sub> )	183°C	217°C
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60-150 seconds	60-150 seconds
Peak Body Package Temperature	235°C+0°C/-5°C	260°C+0°C/-5°C
Time (t <sub>P</sub> ) within 5°C of 260°C	20 seconds	30 seconds
Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )	6°C/second max.	6°C/second max.
Time 25°C to Peak Temperature	6 minutes max.	8 minutes max.

Note:

1. Reflow soldering is recommended at the temperatures and times shown, no more than three times.
2. Avoid direct contact between the epoxy body and any tools or surfaces exceeding its maximum storage temperature.
3. Application of pressure on the epoxy body is prohibited at elevated temperatures. In specific scenarios, any applied force must not exceed 2.5N.
4. Ensure the component has cooled to ambient temperature before proceeding with any subsequent manufacturing steps.
5. The component has a shelf life of one year when stored under standard conditions.
6. Recommend storage Temp.: 0~40°C;  
Recommend storage humidity: <60%;  
MSL level: MSL 1

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